NSN 5961-01-058-7788

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Between 0.115 inches and 0.150 inches

Inclosure Material:

Overall Length:

Terminal Length:

0.500 inches

Metal



View Online at https://aerobasegroup.com/nsn/5961-01-058-7788

Overall Diameter:
Between 0.209 inches and 0.230 inches
End Application:
E-2c hawkeye aircraft
Internal Configuration:
Field effect
Electrode Internally-electrically Connected To Case:
Gate
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
25.0 drain to source voltage and -25.0 gate to source voltage and -25.0 gate non-trigger voltage, dc
Current Rating Per Characteristic:
100.00 milliamperes gate current
Power Rating Per Characteristic:
300.0 milliwatts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Special Features:
Weapon system essential
Test Data Document:
99971-7536462 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
- -

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No

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